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February 2008

MM74HC125, MM74HC126 3-STATE Quad Buffers

Features

■ Typical propagation delay: 13ns
 ■ Wide operating voltage range: 2V–6V
 ■ Low input current: 1µA maximum

■ Low quiescent current: 80µA maximum (74HC)

■ Fanout of 15 LS-TTL loads

General Description

The MM74HC125 and MM74HC126 are general purpose 3-STATE high speed non-inverting buffers utilizing advanced silicon-gate CMOS technology. They have high drive current outputs which enable high speed operation even when driving large bus capacitances. These circuits possess the low power dissipation of CMOS circuitry, yet have speeds comparable to low power Schottky TTL circuits. Both circuits are capable of driving up to 15 low power Schottky inputs.

The MM74HC125 require the 3-STATE control input C to be taken high to put the output into the high impedance condition, whereas the MM74HC126 require the control input to be low to put the output into high impedance.

All inputs are protected from damage due to static discharge by diodes to V_{CC} and ground.

Ordering Information

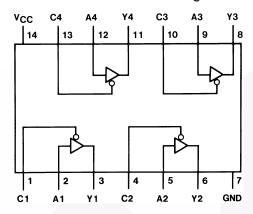
Order Number	Package Number	Package Description
MM74HC125M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC125SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC125MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC125N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
MM74HC126M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC126SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC126MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC126N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.

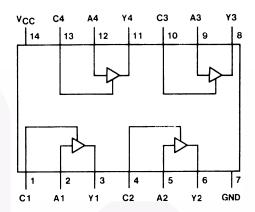
All packages are lead free per JEDEC: J-STD-020B standard.

Connection Diagrams

Pin Assignments for DIP, SOIC, SOP and TSSOP



Top View (MM74HC125)



Top View (MM74HC126)

Truth Tables

Inp	Output	
Α	Y	
Н	L	Н
L	L	L
Х	Н	Z

MM74HC125

Inp	Output	
Α	Υ	
Н	Н	Н
L	Н	L
Х	L	Z

MM74HC126

Absolute Maximum Ratings⁽¹⁾

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	-0.5 to +7.0V
V _{IN}	DC Input Voltage	–1.5 to V _{CC} +1.5V
V _{OUT}	DC Output Voltage	–0.5 to V _{CC} +0.5V
I _{IK} , I _{OK}	Clamp Diode Current	±20mA
I _{OUT}	DC Output Current, per pin	35mA
I _{CC}	DC V _{CC} or GND Current, per pin	±70mA
T _{STG}	Storage Temperature Range	−65°C to +150°C
P _D	Power Dissipation Note 2	600mW
	S.O. Package only	500mW
TL	Lead Temperature (Soldering 10 seconds)	260°C

Notes:

- 1. Unless otherwise specified all voltages are referenced to ground.
- 2. Power Dissipation temperature derating plastic "N" package: -12mW/°C from 65°C to 85°C.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Units
V _{CC}	Supply Voltage	2	6	V
V _{IN} , V _{OUT}	DC Input or Output Voltage	0	V _{CC}	V
T _A	Operating Temperature Range	-40	+85	°C
t _r , t _f	Input Rise or Fall Times			
	$V_{CC} = 2.0V$		1000	ns
	V _{CC} = 4.5V		500	ns
	V _{CC} = 6.0V		400	ns

DC Electrical Characteristics⁽³⁾

				T _A =	25°C	T _A =-40°C to 85°C	T _A = -40°C to 125°C	
Symbol	Parameter	Conditions	V _{CC} (V)	Тур.		Guaranteed	Limits	Units
V _{IH}	Minimum HIGH		2.0		1.5	1.5	1.5	V
	Level Input Voltage		4.5		3.15	3.15	3.15	
	Voltage		6.0		4.2	4.2	4.2	
V _{IL}	Maximum LOW		2.0		0.5	0.5	0.5	V
	Level Input Voltage		4.5		1.35	1.35	1.35	
	Voltage		6.0		1.8	1.8	1.8	
V _{OH}	Minimum HIGH	$V_{IN} = V_{IH} \text{ or } V_{IL},$	2.0	2.0	1.9	1.9	1.9	V
	Level Output Voltage	I _{OUT} ≤ 20µA	4.5	4.5	4.4	4.4	4.4	
	voitage		6.0	6.0	5.9	5.9	5.9	
		$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT} \le 6.0 \text{mA}$	4.5	4.2	3.98	3.84	3.7	
	3	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT} \le 7.8 \text{mA}$	6.0	5.7	5.48	5.34	5.2	
V _{OL}	Maximum LOW Level Output Voltage	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT} \le 20 \mu A$	2.0	0	0.1	0.1	0.1	V
			4.5	0	0.1	0.1	0.1	
			6.0	0	0.1	0.1	0.1	
		$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT} \le 6.0 \text{mA}$	4.5	0.2	0.26	0.33	0.4	
		$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT} \le 7.8 \text{mA}$	6.0	0.2	0.26	0.33	0.4	
I _{OZ}	Maximum 3-STATE Output Leakage Current	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $V_{OUT} = V_{CC} \text{ or GND,}$ $C_n = \text{Disabled}$	6.0		±0.5	±5	±10	μA
I _{IN}	Maximum Input Current	$V_{IN} = V_{CC}$ or GND	6.0		±0.1	±1.0	±1.0	μA
I _{CC}	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0\mu A$	6.0		8.0	80	160	μA

Note:

3. For a power supply of 5V $\pm 10\%$ the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC}=5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

 $V_{CC} = 5V$, $T_A = 25^{\circ}C$, $C_L = 45pF$, $t_r = t_f = 6ns$

Symbol	Parameter	Conditions	Тур.	Guaranteed Limit	Units
t _{PHL} , t _{PLH}	Maximum Propagation Delay Time		13	18	ns
t _{PZH}	Maximum Output Enable Time to HIGH Level	$R_L = 1k\Omega$	13	25	ns
t _{PHZ}	Maximum Output Disable Time from HIGH Level	$R_L = 1k\Omega$, $C_L = 5pF$	17	25	ns
t _{PZL}	Maximum Output Enable Time to LOW Level	$R_L = 1k\Omega$	18	25	ns
t _{PLZ}	Maximum Output Disable Time from LOW Level	$R_L = 1k\Omega$, $C_L = 5pF$	13	25	ns

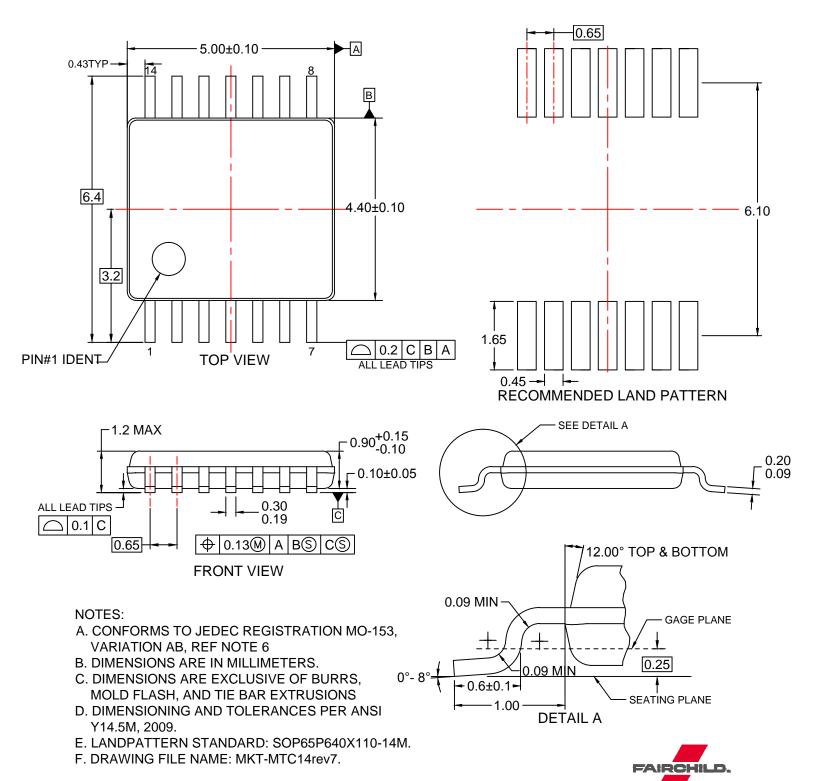
AC Electrical Characteristics

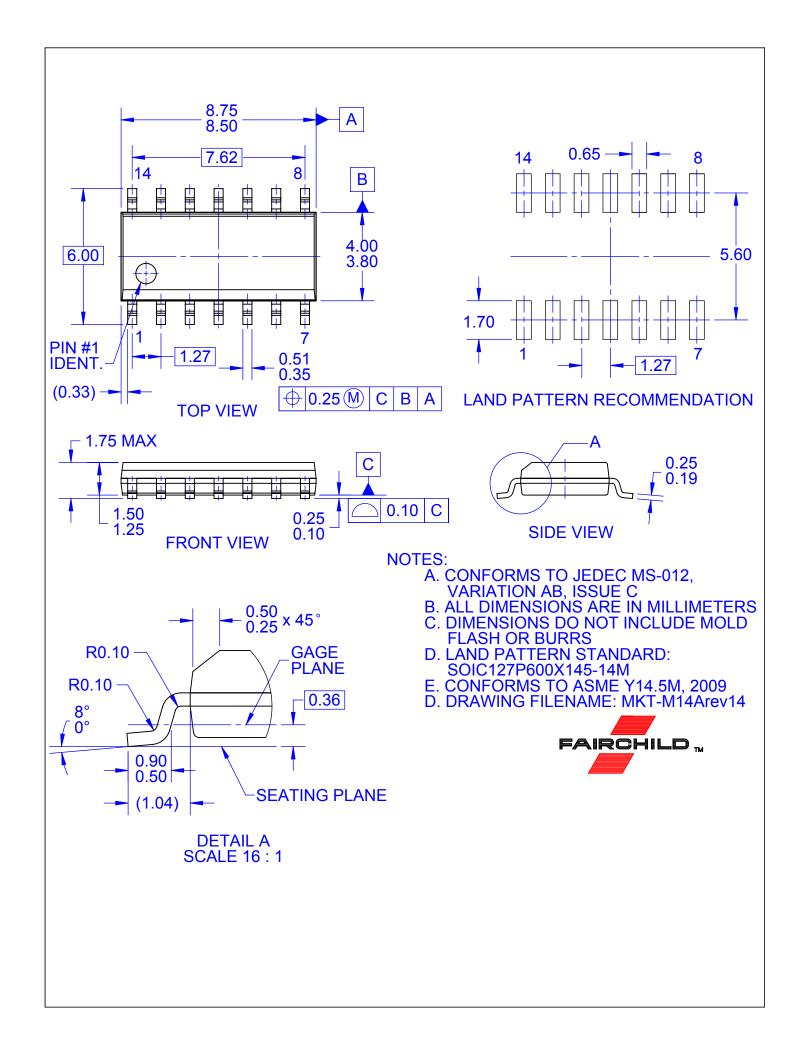
 V_{CC} = 2.0V to 6.0V, C_L = 50pF, t_r = t_f = 6ns (unless otherwise specified)

				T _A =	25°C	T _A = -40°C to 85°C	T _A = -40°C to 125°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Тур.		Guaranteed	Limits	Units
t _{PHL} , t _{PLH}	Maximum Propagation	2.0		40	100	125	150	ns
	Delay Time	4.5		14	20	25	30	
		6.0		12	17	21	25	
t _{PLH} , t _{PHL}	Maximum Propagation	2.0	C _L = 150pF	35	130	163	195	ns
	Delay Time	4.5		14	26	33	39	
		6.0		12	22	28	39	
t_{PZH}, t_{PZL}	Maximum Output	2.0	$R_L = 1k\Omega$	25	125	156	188	ns
	Enable Time	4.5		14	25	31	38	
		6.0		12	21	26	31	
t _{PHZ} , t _{PLZ}	Maximum Output	2.0	$R_L = 1k\Omega$	25	125	156	188	ns
	Disable Time	4.5		14	25	31	38	
		6.0		12	21	26	31	
t _{PZL} , t _{PZH}	Maximum Output	2.0	$C_L = 150 pF,$	35	140	175	210	ns
	Enable Time	4.5	$R_L = 1k\Omega$	15	28	35	42	
		6.0		13	24	30	36	
t _{TLH} , t _{THL}	Maximum Output	2.0V	$C_L = 50pF$	30	60	75	90	ns
	Rise and Fall Time	4.5V		7	12	15	18	
		6.0V		6	10	13	15	
C _{IN}	Input Capacitance			5	10	10	10	pF
C _{OUT}	Output Capacitance Outputs			15	20	20	20	pF
C _{PD}	Power Dissipation		Enabled	45				pF
	Capacitance (per gate) ⁽⁴⁾		Disabled	6				

Note:

4. C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} \ V_{CC}^2 f + I_{CC} \ V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} \ V_{CC} \ f + I_{CC}$.





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